Old Company Name in Catalogs and Other Documents

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Renesas Electronics website: http://www.renesas.com

April 1st, 2010 Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (http://www.renesas.com)

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HAT2168N

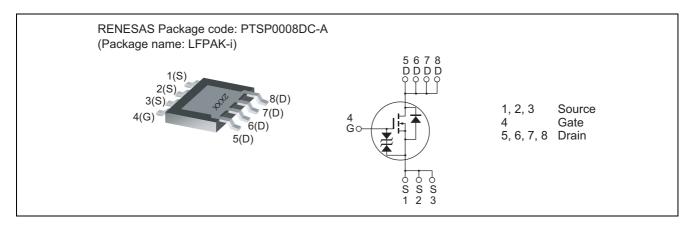
Silicon N Channel Power MOS FET Power Switching

REJ03G1682-0200 Rev.2.00 May 27, 2008

Features

- High speed switching
- Capable of 4.5 V gate drive
- Low drive current
- High density mounting
- Low on-resistance
 - $R_{DS(on)}\!=6.3~\text{m}\Omega$ typ. (at $V_{GS}\!=10~\text{V})$
- Power Supply for Server and Telecom (Indoor use)

Outline



Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

Item	Symbol	Ratings	Unit
Drain to source voltage	V _{DSS}	30	V
Gate to source voltage	V _{GSS}	±20	V
Drain current	I _D	30	A
Drain peak current	I _{D(pulse)} Note1	120	А
Body-drain diode reverse drain current	I _{DR}	30	A
Avalanche current	I _{AP} Note 2	15	A
Avalanche energy	E _{AR} Note 2	22	mJ
Channel dissipation	Pch Note3	15	W
Channel to case thermal resistance	θch-C	8.33	°C/W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	- 55 to + 150	°C

Notes: 1. PW \leq 10 μ s, duty cycle \leq 1%

- 2. Value at Tch = 25°C, Rg \geq 50 Ω
- 3. $Tc = 25^{\circ}C$

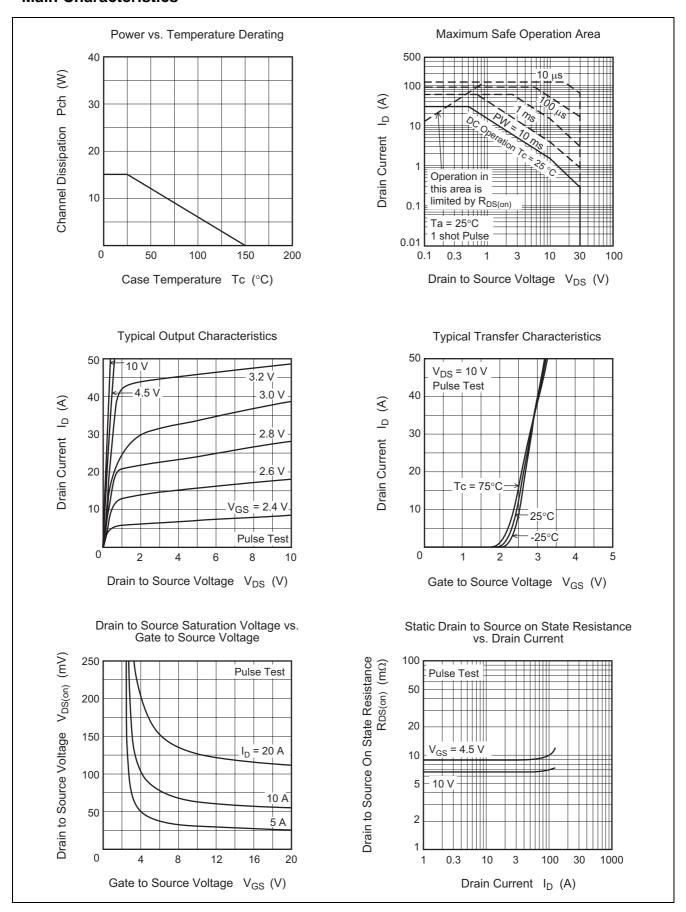
Electrical Characteristics

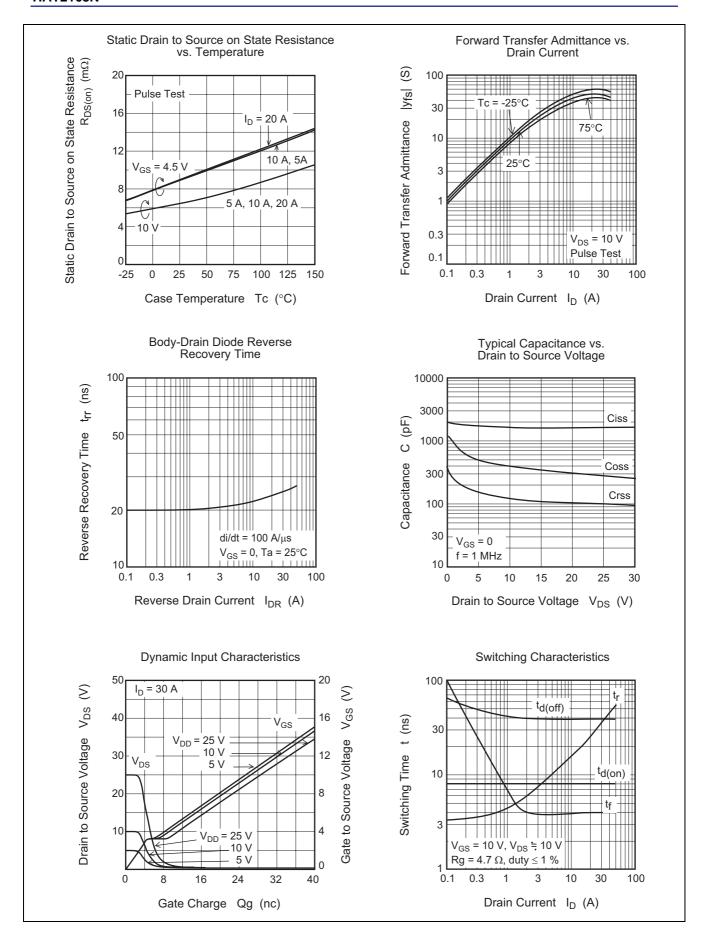
 $(Ta = 25^{\circ}C)$

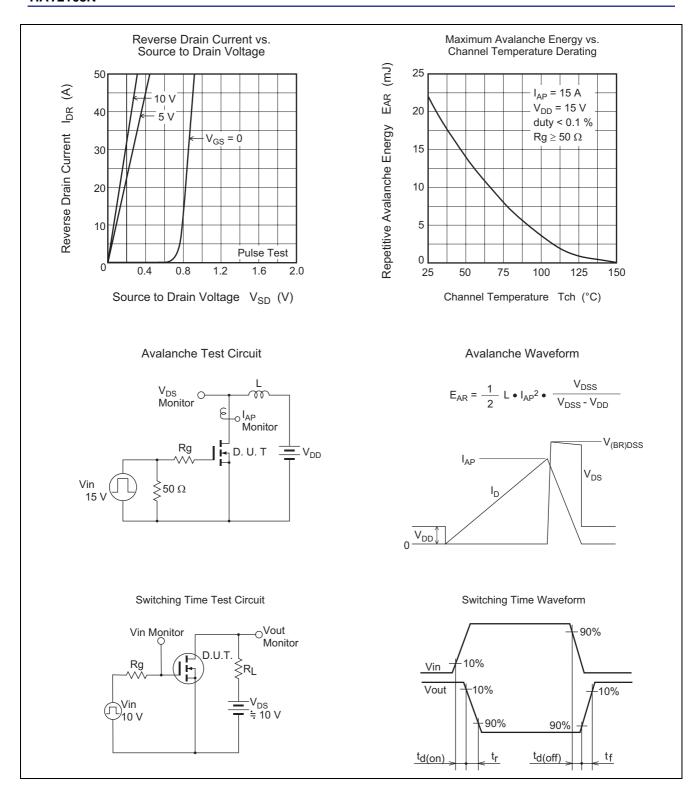
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Drain to source breakdown voltage	V _{(BR)DSS}	30	_	_	V	$I_D = 10 \text{ mA}, V_{GS} = 0$
Gate to source breakdown voltage	$V_{(BR)GSS}$	±20	_	_	V	$I_G = \pm 100 \ \mu A, \ V_{DS} = 0$
Gate to source leak current	I _{GSS}	_	_	±10	μΑ	$V_{GS} = \pm 16 \text{ V}, V_{DS} = 0$
Zero gate voltage drain current	I _{DSS}	_	_	1	μΑ	$V_{DS} = 30 \text{ V}, V_{GS} = 0$
Gate to source cutoff voltage	$V_{GS(off)}$	1.0	_	2.5	V	$V_{DS} = 10 \text{ V}, I_{D} = 1 \text{ mA}$
Static drain to source on state	R _{DS(on)}	_	6.3	8.2	mΩ	$I_D = 15 \text{ A}, V_{GS} = 10 \text{ V}^{Note4}$
resistance	R _{DS(on)}	_	9.1	13.8	mΩ	$I_D = 15 \text{ A}, V_{GS} = 4.5 \text{ V}^{\text{Note4}}$
Forward transfer admittance	y _{fs}	30	50	_	S	$I_D = 15 \text{ A}, V_{DS} = 10 \text{ V}^{\text{Note4}}$
Input capacitance	Ciss	_	1730	_	pF	V _{DS} = 10 V
Output capacitance	Coss	_	400	_	pF	V _{GS} = 0 f = 1 MHz
Reverse transfer capacitance	Crss	_	130	_	pF	
Gate Resistance	Rg	_	0.55	_	Ω	
Total gate charge	Qg	_	11	_	nc	V _{DD} = 10 V
Gate to source charge	Qgs	_	5	_	nc	$V_{GS} = 4.5 \text{ V}$ $I_{D} = 30 \text{ A}$
Gate to drain charge	Qgd	_	2.4	_	nc	
Turn-on delay time	t _{d(on)}	_	8	_	ns	$V_{GS} = 10 \text{ V}, I_D = 15 \text{ A}$
Rise time	t _r	_	20	_	ns	$V_{DD} \cong 10 \text{ V}$ $R_L = 0.67 \Omega$ $Rg = 4.7 \Omega$
Turn-off delay time	t _{d(off)}	_	40	_	ns	
Fall time	t _f	_	4	_	ns	
Body-drain diode forward voltage	V_{DF}	_	0.85	1.10	V	$I_F = 30 \text{ A}, V_{GS} = 0^{\text{Note4}}$
Body-drain diode reverse recovery	t _{rr}	_	25	_	ns	$I_F = 30 \text{ A}, V_{GS} = 0$
time						di _F / dt = 100 A/ μs

Notes: 4. Pulse test

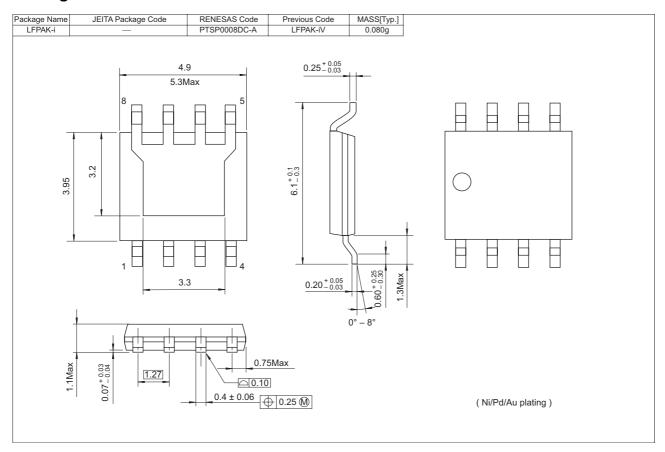
Main Characteristics







Package Dimensions



Ordering Information

Part No.	Quantity	Shipping Container
HAT2168N-EL-E	2500 pcs	Taping

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